# Recent Papers by IBM Authors

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• Papers are listed alphabetically by name of journal.

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Reflective Multilayer Coatings for the Far uv Region, E. Spiller (RES Yorktown Hts., NY), *Applied Optics* 15, No. 10, 2333-2338 (October 1976).

Shock Wave Introduction of Gas into Relativistic e-Beam-Pumped Lasers and Drift Tubes, R. W. Dreyfus (RES Yorktown Hts., NY), Applied Physics Letters 29, No. 6, 348-350 (September 15, 1976).

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Semiconductor Devices: A Bibliography of Fabrication Technology, Properties, and Applications, A. H. Agajanian (SPD East Fishkill, NY), Plenum Publishing Co., New York, 1976, 944 pp.

A compilation is made of over 14000 literature references on the theory, preparation, properties, characterization, modeling, packaging, instrumentation, and applications of semiconducting devices. The period 1967 to 1975 is covered, and selected references are included also prior to 1967. A comprehensive subject index is provided for the journal papers and books listed.

Software Reliability: Principles and Practices, G. J. Myers (IBM Systems Research Institute, New York, NY), John Wiley & Sons, Inc., New York, 1976.

This book is concerned with major strategical approaches to the production of reliable software and also with smaller-scale tactical solutions to various aspects of the unreliability problem. The first part discusses principal causes of software errors. Part 2 contains a large set of principles and practices used in the design of reliable software. The third part covers the broad area of software testing, including some proven principles. Part 4 discusses other variables that affect reliability, including organizational structures, personalities, attitudes, management plans and motivation, programming tools, and the work environment. The subject of reliability is treated solely from the viewpoint of software errors and does not cover the use of software to correct or circumvent hardware failures.

Telecommunications and the Computer, 2nd edition, James Martin (IBM Systems Research Institute, New York, NY), Prentice-Hall, Inc., Englewood Cliffs, NJ, 1976, 676 pp.

The second edition is an updated, detailed review of the workings of telecommunications lines and of their use for data transmission. Included are recent developments in transmission and switching and a discussion of practical communications techniques for new common carrier equipment. The chapter on transmission reviews current aspects of network structure, ac and dc transmission, attenuation and repeaters, frequency, and bandwidth. The chapter on switching technology covers several types, including pocket switching networks. A newly added chapter on imperfections in lines and systems deals with noise and distortion, line failures, data errors, and delays and blocking.